NSN 5961-01-355-0506

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-355-0506 **Inclosure Material:** Metal or plastic **Overall Length:** 0.750 inches **Overall Height:** 0.620 inches **Overall Width:** 0.750 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Component Name And Quantity:** 8 semiconductor device diode **Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case and quality assurance level tx **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 6.0 working peak reverse voltage 5th semiconductor device diode **Current Rating Per Characteristic:** 5.00 microamperes forward current, average peak 5th transistor **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 8 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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